

PJA3420E

20V N-Channel Enhancement Mode MOSFET– ESD Protected

Voltage

20 V

Current

5.1 A

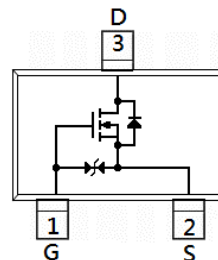
Features

- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@5.1A < 27m\Omega$
- $R_{DS(ON)}$, $V_{GS}@2.5V$, $I_D@3.2A < 33m\Omega$
- $R_{DS(ON)}$, $V_{GS}@1.8V$, $I_D@2.0A < 46m\Omega$
- Advanced Trench Process Technology
- ESD Protected HBM Class 1C
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0084 grams

SOT-23



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V _{GS}	±8	
Continuous Drain Current ^(Note 4)	T _A =25°C	I _D	5.1	A
	T _A =70°C		4.1	
Pulsed Drain Current ^(Note 1)	T _A =25°C	I _{DM}	20	
Power Dissipation	T _A =25°C	P _D	1.3	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient ^(Note 5)		R _{θJA}	100	°C/W

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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	0.4	0.67	0.9	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =5.1A	-	22	27	mΩ
		V _{GS} =2.5V, I _D =3.2A	-	26	33	
		V _{GS} =1.8V, I _D =2.0A	-	34	46	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V	-	-	±10	
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =10V, I _D =5.2A, V _{GS} =4.5V ^(Note 2,3)	-	6.3	-	nC
Gate-Source Charge	Q _{gs}		-	1.2	-	
Gate-Drain Charge	Q _{gd}		-	1.0	-	
Input Capacitance	C _{iss}	V _{DS} =10V, V _{GS} =0V, f=1MHZ	-	515	-	pF
Output Capacitance	C _{oss}		-	60	-	
Reverse Transfer Capacitance	C _{rss}		-	47	-	
Turn-On Delay Time	t _{d(on)}	V _{DS} =10V, I _D =5.2A, V _{GS} =4.5V, R _G =6Ω ^(Note 2,3)	-	7	-	ns
Turn-On Rise Time	t _r		-	43	-	
Turn-Off Delay Time	t _{d(off)}		-	170	-	
Turn-Off Fall Time	t _f		-	13	-	
Drain-Source Diode						
Diode Forward Current	I _S	T _A =25°C	-	-	1.5	A
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.76	1.2	V

Notes :

- 1.Pulse width<300us, Duty cycle<2%.
- 2.Essentially independent of operating temperature typical characteristics.
- 3.Repetitive rating, pulse width limited by junction temperature $T_J(\text{MAX})=150^{\circ}\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^{\circ}\text{C}$.
- 4.The maximum current rating is package limited.
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6.Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

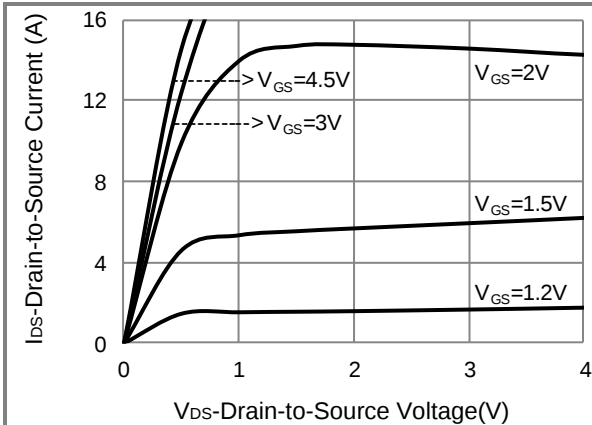


Fig.1 Output Characteristics

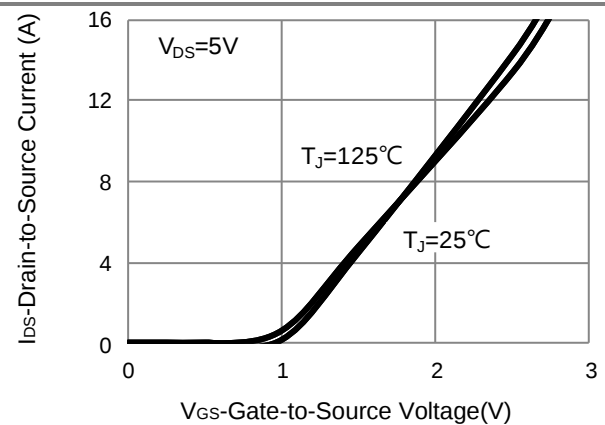


Fig.2 Transfer Characteristics

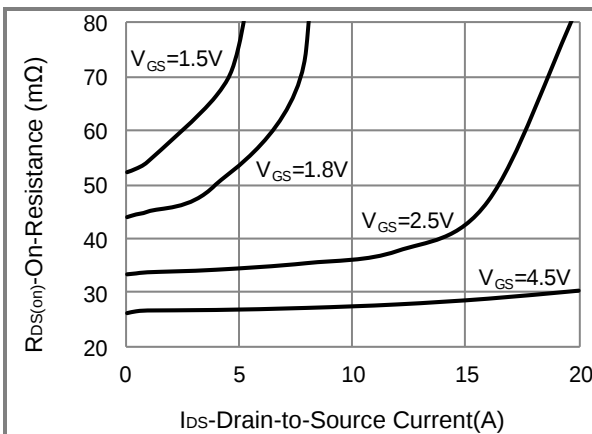


Fig.3 On-Resistance vs. Drain Current

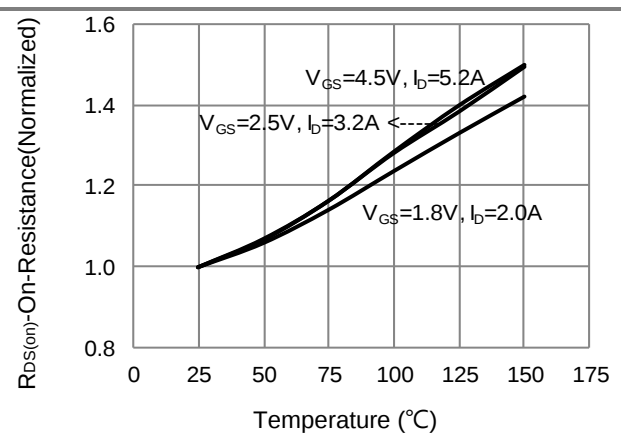


Fig.4 On-Resistance vs. Junction temperature

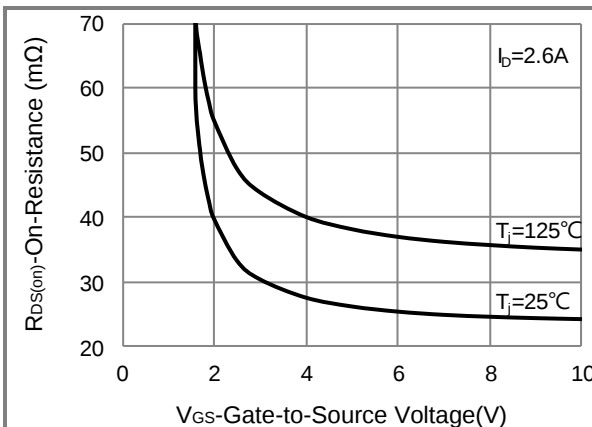


Fig.5 On-Resistance Variation with V_{GS}

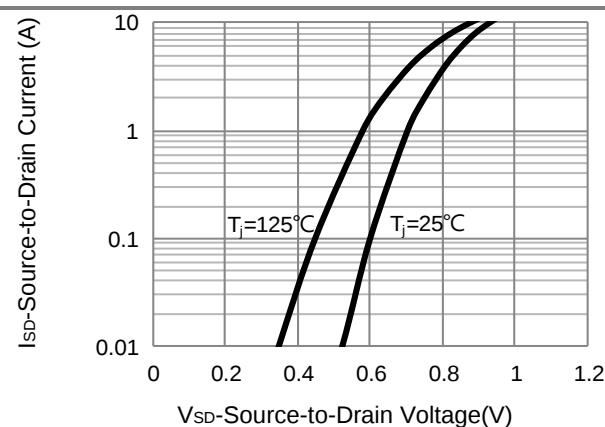


Fig.6 Body Diode Characteristic

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TYPICAL CHARACTERISTIC CURVES

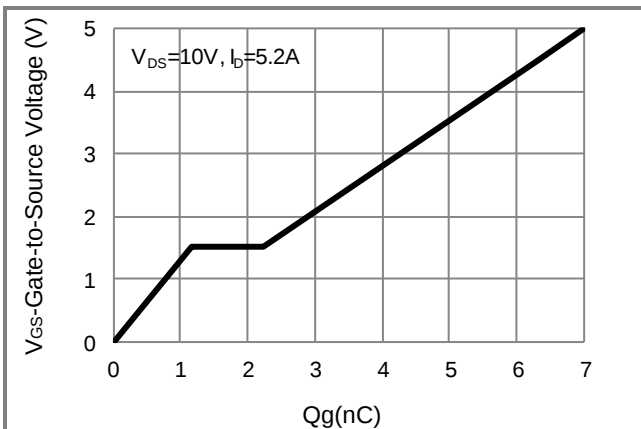


Fig.7 Gate-Charge Characteristics

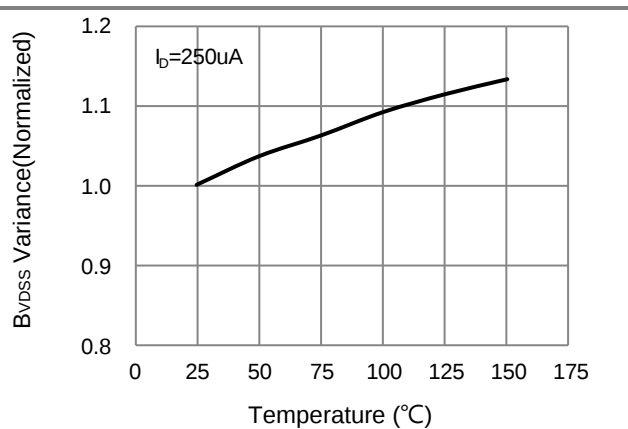


Fig.8 Breakdown Voltage Variation vs. Temperature

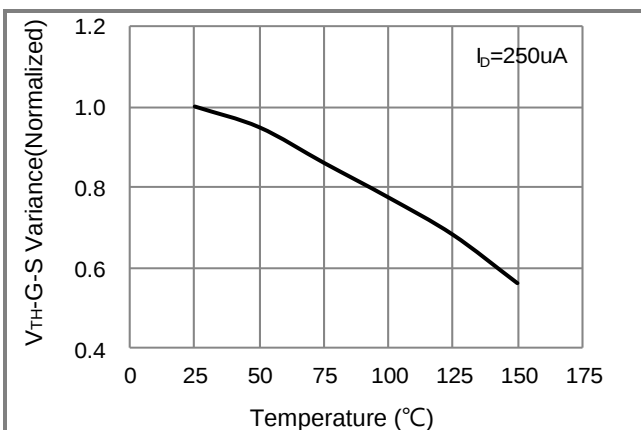


Fig.9 Threshold Voltage Variation with Temperature

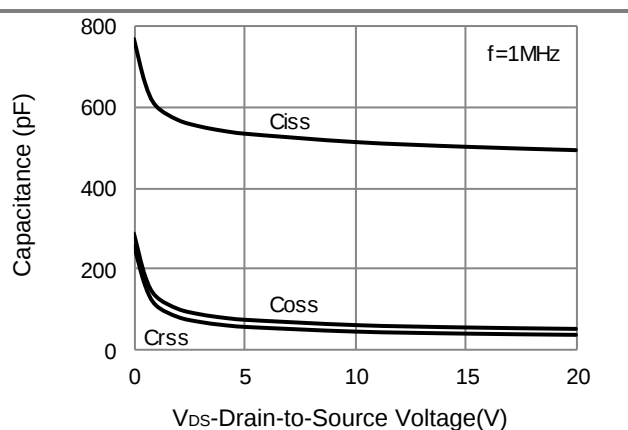


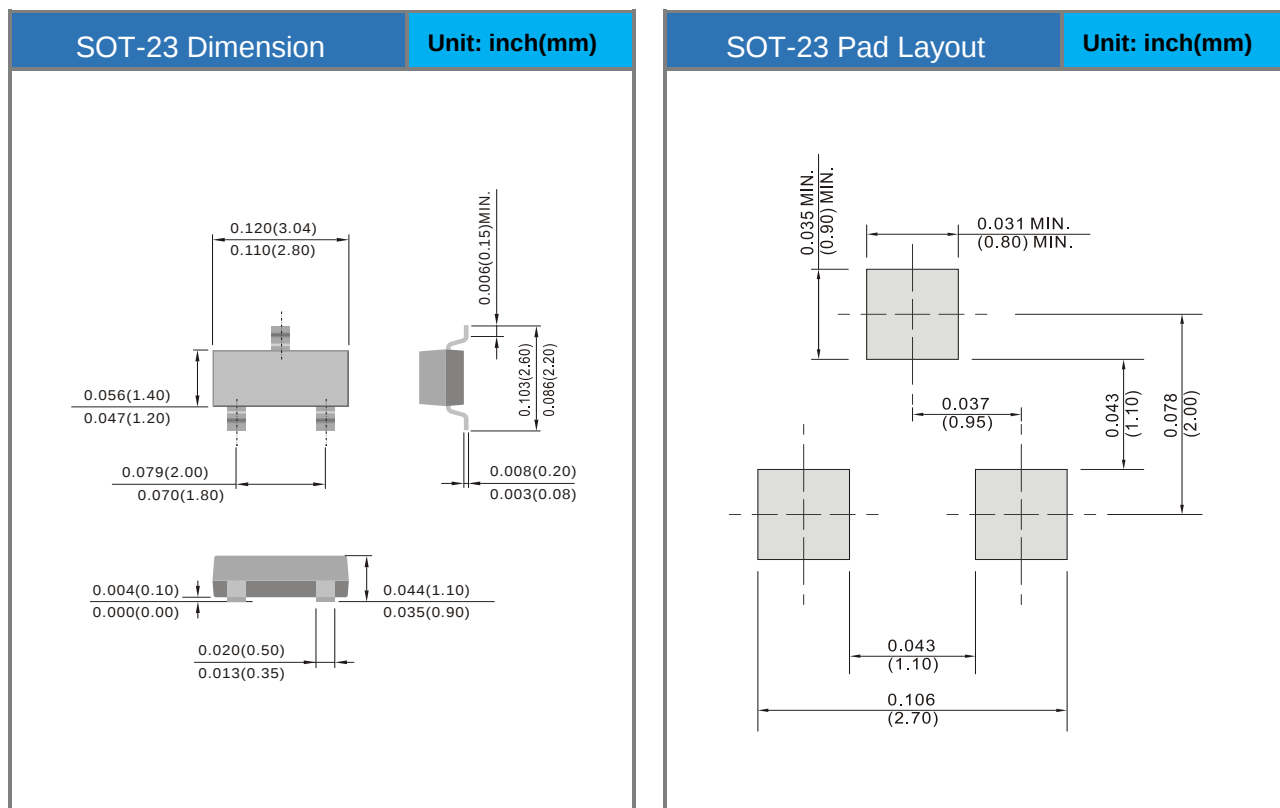
Fig.10 Capacitance vs. Drain-Source Voltage

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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJA3420E	SOT-23	3K pcs / 7" reel	20E

Packaging Information & Mounting Pad Layout



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